NSN 5961-01-364-7863

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-364-7863 **Inclosure Material:** Metal **Overall Length:** Between 4.905 inches and 5.710 inches **Function For Which Designed:** Rectifier **End Application:** Mk73/1 dcn **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: D0-205aa **Mounting Method:** Threaded stud **Overall Width Across Flats:** Between 1.031 inches and 1.063 inches Thready Qty Per Inch (tpi): 24 **Thread Size:** 0.375 inches **Thread Pitch In Millimeters:** 8.84 **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1200.0 nonrepetitive peak reverse voltage and 1000.0 working peak reverse voltage **Current Rating Per Characteristic:** 75.00 amperes collector current, dc absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Thread Series Designator: Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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